

FJN3303FBU Datasheet

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DiGi Electronics Part Number	FJN3303FBU-DG
Manufacturer	onsemi
Manufacturer Product Number	FJN3303FBU
Description	TRANS NPN 400V 1.5A TO92-3
Detailed Description	Bipolar (BJT) Transistor NPN 400 V 1.5 A 4MHz 650 mW Through Hole TO-92-3



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Purchase and inquiry

Manufacturer Product Number:

FJN3303FBU

Series:

-

Transistor Type:

NPN

Voltage - Collector Emitter Breakdown (Max):

400 V

Current - Collector Cutoff (Max):

10 μ A (ICBO)

Power - Max:

650 mW

Operating Temperature:

150°C (TJ)

Package / Case:

TO-226-3, TO-92-3 (TO-226AA)

Base Product Number:

FJN330

Manufacturer:

onsemi

Product Status:

Obsolete

Current - Collector (Ic) (Max):

1.5 A

Vce Saturation (Max) @ Ib, Ic:

3V @ 500mA, 1.5A

DC Current Gain (hFE) (Min) @ Ic, Vce:

14 @ 500mA, 2V

Frequency - Transition:

4MHz

Mounting Type:

Through Hole

Supplier Device Package:

TO-92-3

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.21.0095

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99



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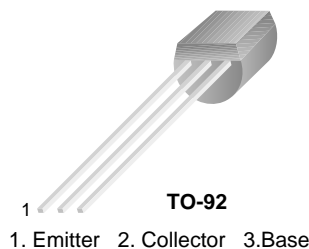
December 2009

FJN3303F

High Voltage Fast-Switching NPN Power Transistor

Features

- High Voltage Capability
- High Switching Speed
- Suitable for Electronic Ballast and Charger
- Green packaging



Absolute Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	700	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	9	V
I_C	Collector Current (DC)	1.5	A
I_{CP}	Collector Current (Pulse) *	3	A
I_B	Base Current (DC)	0.75	A
I_{BP}	Base Current (Pulse) *	1.5	A
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature range	-65 to +150	$^\circ\text{C}$

* Pulse Test: Pulse Width = 5ms, Duty Cycle \leq 10%

Thermal Characteristics $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units	
P_D	Total Device Dissipation	$T_C = 25^\circ\text{C}$	1.1	W
		$T_A = 25^\circ\text{C}$	650	mW
$R_{\theta JC}$	Thermal Resistance Junction-Case	48	$^\circ\text{C}/\text{W}$	
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	190	$^\circ\text{C}/\text{W}$	

Ordering Information

Part Number	Marking Info.	Package	Packing Method	Remarks
FJN3303FBU	J3303F	TO-92 (Straight)	BULK	Green EMC
FJN3303FTA	J3303F	TO-92 (Form)	AMMO	Green EMC

Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C = 500\mu\text{A}, I_E = 0$	700			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 5\text{mA}, I_B = 0$	400			V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E = 500\mu\text{A}, I_C = 0$	9			V
I_{CBO}	Collector Cut-off Current	$V_{CB} = 700\text{V}, I_E = 0$			10	μA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = 9\text{V}, I_C = 0$			10	μA
h_{FE1} h_{FE2}	DC Current Gain	$V_{CE} = 2\text{V}, I_C = 0.5\text{A}$ $V_{CE} = 2\text{V}, I_C = 1.0\text{A}$	14 5		23	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 0.5\text{A}, I_B = 0.1\text{A}$ $I_C = 1.0\text{A}, I_B = 0.25\text{A}$ $I_C = 1.5\text{A}, I_B = 0.5\text{A}$			0.5 1.0 3.0	V V V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 0.5\text{A}, I_B = 0.1\text{A}$ $I_C = 1.0\text{A}, I_B = 0.25\text{A}$			1.0 1.2	V V
f_T	Current Gain Bandwidth Product	$V_{CE} = 10\text{V}, I_C = 0.1\text{A}$	4			MHz
t_{ON}	Turn On Time	$V_{CC} = 125\text{V}, I_C = 1\text{A}$			1.1	μs
t_{STG}	Storage Time	$I_{B1} = -I_{B2} = -0.2\text{A}$			4.0	μs
t_F	Fall Time	$R_L = 125\Omega$			0.7	μs

Typical Performance Characteristics

Figure 1. Static Characteristic

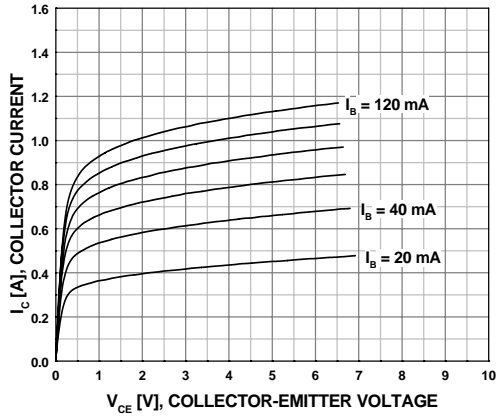


Figure 2. DC Current Gain

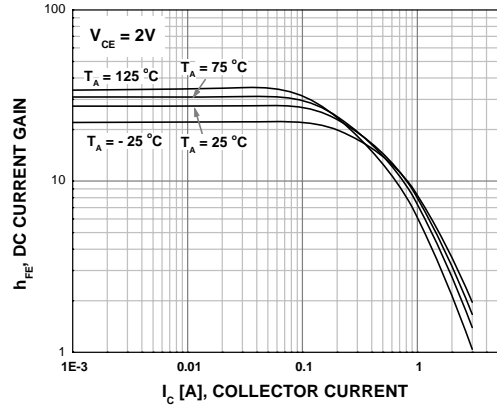


Figure 3. Collector-Emitter Saturation Voltage

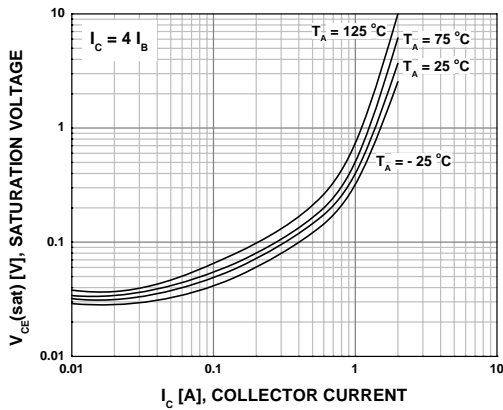


Figure 4. Base-Emitter Saturation Voltage

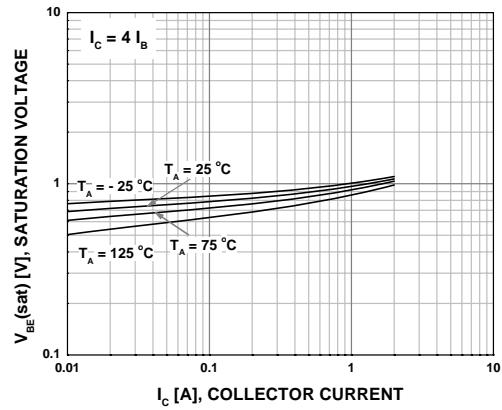


Figure 5. Resistive Load Switching Time

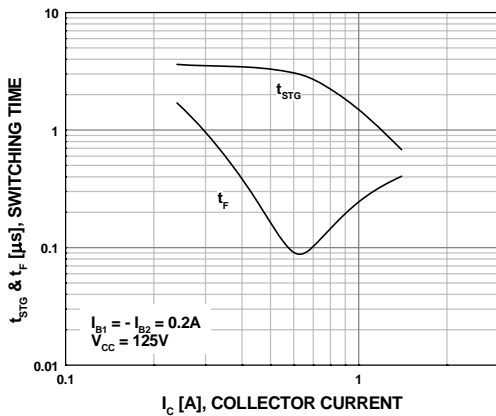
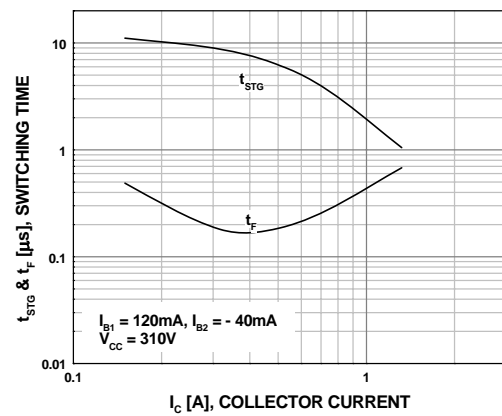


Figure 6. Resistive Load Switching Time



Typical Performance Characteristics (Continued)

Figure 7. Forward Biased Safe Operating Area

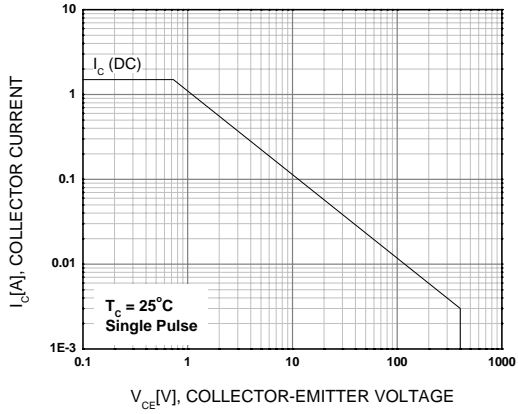


Figure 8. Reverse Biased Safe Operating Area

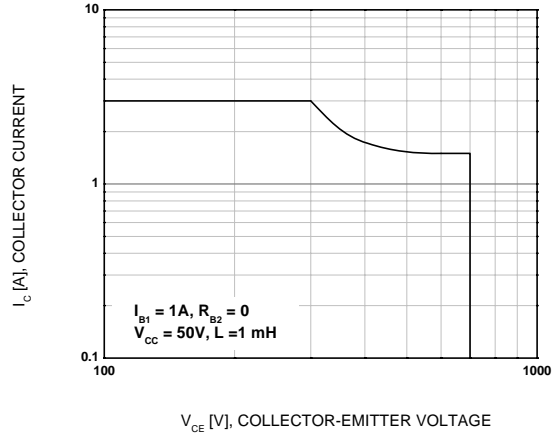
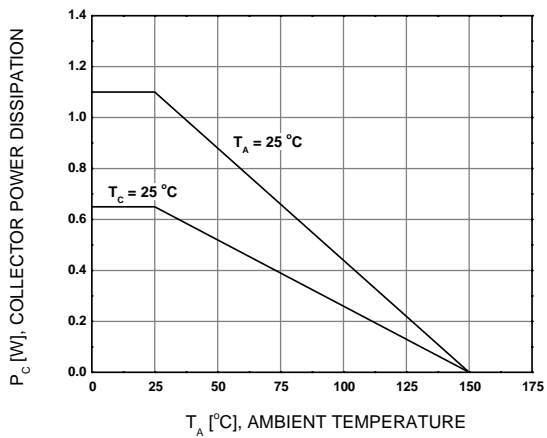
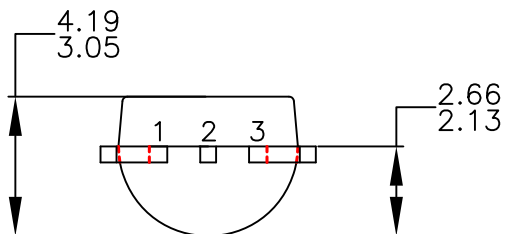
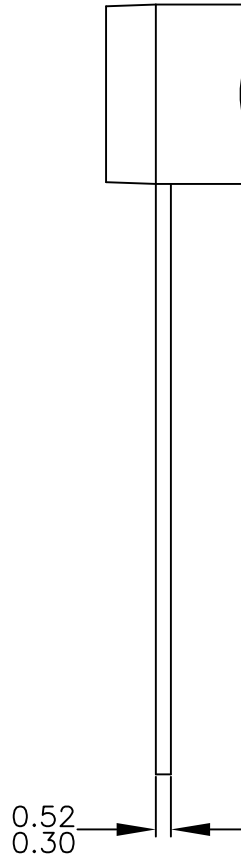
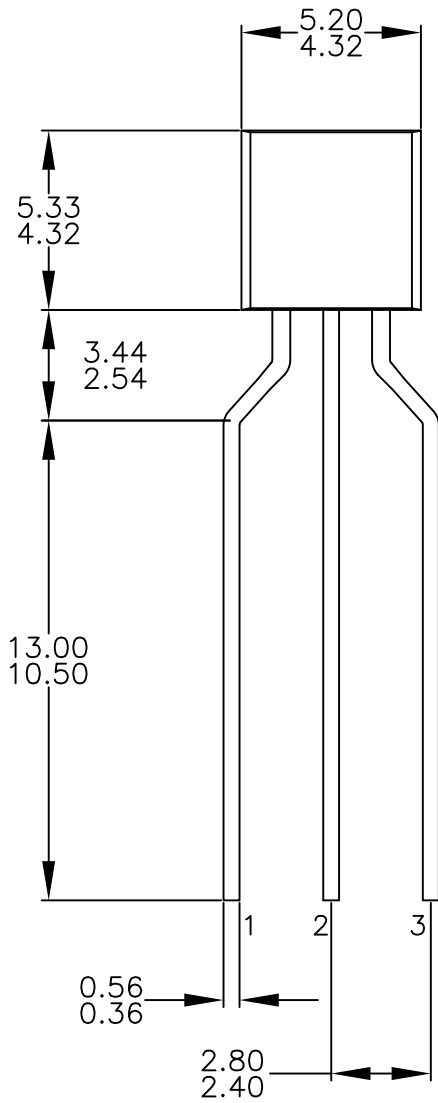


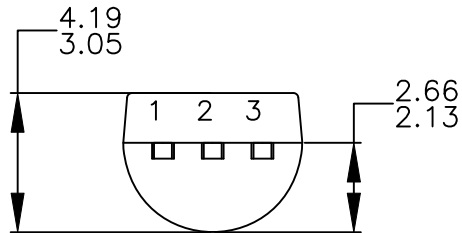
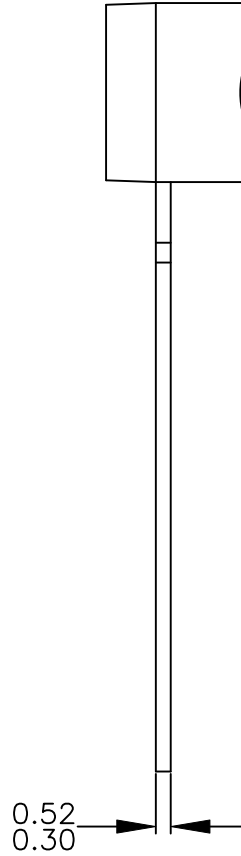
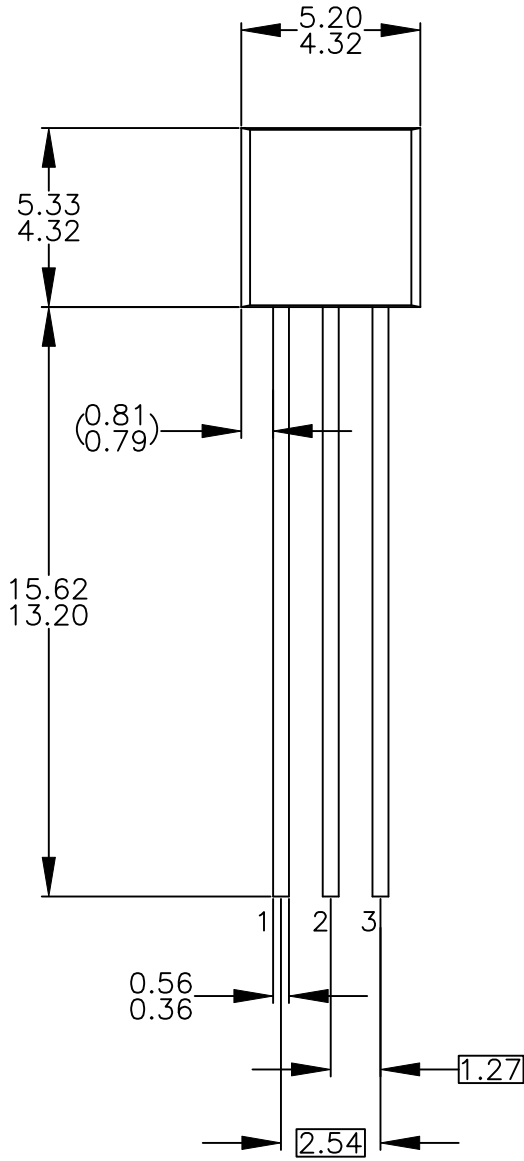
Figure 9. Power Derating





NOTES: UNLESS OTHERWISE SPECIFIED


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- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DRAWING CONFORMS TO ASME Y14.5M-2009.
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